

www.vishay.com

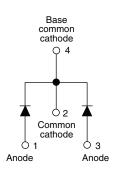
Vishay Semiconductors

COMPLIANT

**HALOGEN** 

## Ultrafast Rectifier, 2 x 3 A FRED Pt®





PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	2 x 3 A							
$V_{R}$	200 V							
V <sub>F</sub> at I <sub>F</sub>	0.9 V							
t <sub>rr</sub> typ.	See Recovery table							
T <sub>J</sub> max.	175 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Common cathode							

### **FEATURES**

- · Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

VS-MURD620CT-M3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS					
Peak repetitive reverse voltage	$V_{RRM}$		200	V					
Average rectified forward current per device	I <sub>F(AV)</sub>	Total device, rated V <sub>R</sub> , T <sub>C</sub> = 146 °C	6						
Non-repetitive peak surge current	I <sub>FSM</sub>		50	Α					
Peak repetitive forward current per diode	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 146 °C	6						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C					

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-				
Forward voltage		I <sub>F</sub> = 3 A	-	0.9	1.0				
	V <sub>F</sub>	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	0.78	0.96	V			
		I <sub>F</sub> = 6 A	-	1	1.2	]			
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	0.89	1.13				
Poversa laskaga surrent	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	5				
Reverse leakage current		$T_J = 125 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	250	μΑ			
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

Revision: 09-Dec-2019 1 Document Number: 93497





www.vishay.com

# Vishay Semiconductors

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A}$	Vμs, V <sub>R</sub> = 30 V	-	-	35				
	t <sub>rr</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>F</sub>	-	-	25					
		T <sub>J</sub> = 25 °C		-	19	-	ns			
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 3 A dI <sub>F</sub> /dt = 200 A/μs	-	26	-				
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.1	-	- A			
		T <sub>J</sub> = 125 °C	$V_{\rm R} = 160 \text{ V}$	-	4.6	-				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	30	-				
		T <sub>J</sub> = 125 °C		-	60	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	9.0					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	80	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	ı	-					
Weight			-	0.3	-	g				
vveignt			-	0.01	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style DPAK (TO-252AA)	MURD620CT			•				

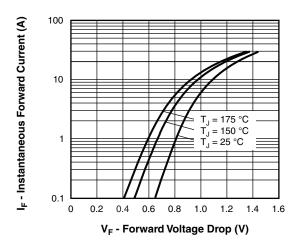


Fig. 1 - Typical Forward Voltage Drop Characteristics

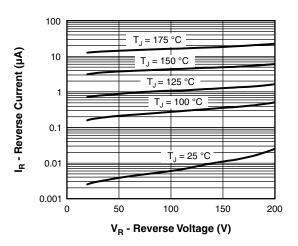


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

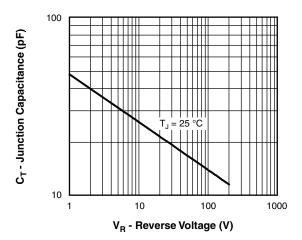


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

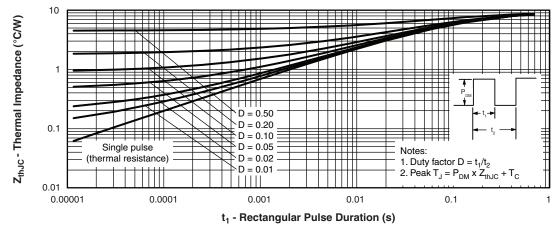


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

Revision: 09-Dec-2019 3 Document Number: 93497 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

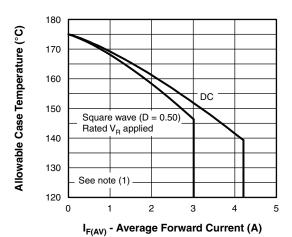


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

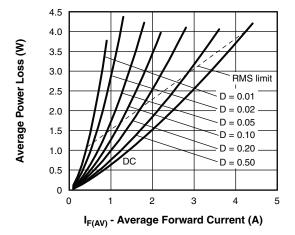


Fig. 6 - Forward Power Loss Characteristics

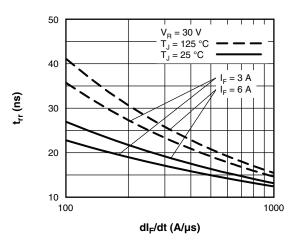


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

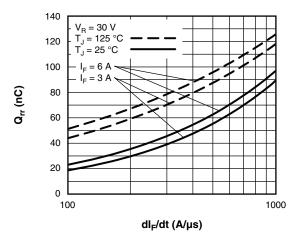


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 

Revision: 09-Dec-2019 **4** Document Number: 93497 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

## www.vishay.com Vishay Semiconductors

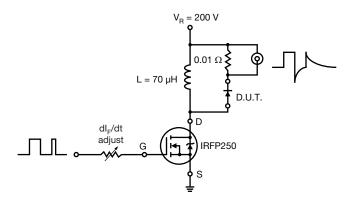
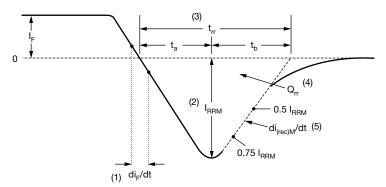


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{rr}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\text{rr}}$  area under curve defined by  $\mathbf{t}_{\text{rr}}$  and  $\mathbf{I}_{\text{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

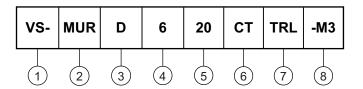
(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Ultrafast MUR series

3 - D = D-PAK

Current rating (6 = 6 A)

5 - Voltage rating (20 = 200 V)

- CT = center tap (dual) TR = tape and reel

TRL = tape and reel (left oriented)
TRR = tape and reel (right oriented)

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MURD620CT-M3	75	3000	Antistatic plastic tube						
VS-MURD620CTTR-M3	2000	2000	13" diameter reel						
VS-MURD620CTTRL-M3	3000	3000	13" diameter reel						
VS-MURD620CTTRR-M3	3000	3000	13" diameter reel						

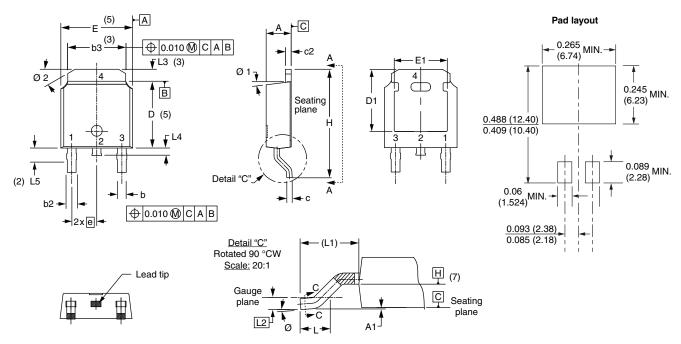
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95627</u>						
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					

Revision: 09-Dec-2019 6 Document Number: 93497



# D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	OTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC		
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410		
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070		
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.		
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020 BSC			
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040		
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2	
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°		
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°		
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°		

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA

Revision: 24-Jun-16 1 Document Number: 95627

## **Legal Disclaimer Notice**



Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2022 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED